

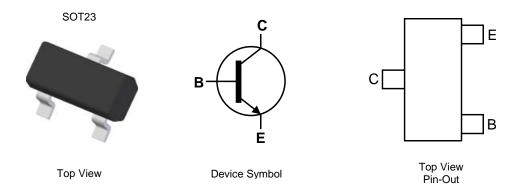
#### **160V NPN SMALL SIGNAL TRANSISTOR IN SOT23**

#### **Features**

- BV<sub>CEO</sub> > 160V
- Ideal for Low Power Amplification and Switching
- Complementary PNP Type Available (MMBT5401)
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

#### **Mechanical Data**

- Case: SOT-23
- Case Material: Molded Plastic, "Green" molding compound.
   UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish-Matte Tin Plated Leads. Solderable per MIL-STD-202, Method 208 (2)
- Weight: 0.008 grams (approximate)



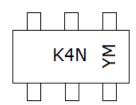
### Ordering Information (Note 4)

Part Number	Compliance	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
MMBT5551-7-F	AEC-Q101	K4N	7	8	3,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

## **Marking Information**



K4N = Product Type Marking Code YM = Date Code Marking Y = Year (ex: B = 2014) M = Month (ex: 9 = September)

Date Code Key

Year	2010		2011	2012		2013	2014		2015	2016		2017
Code	X		Υ	Z		Α	В		С	D		E
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



### **Absolute Maximum Ratings** (@T<sub>A</sub> = +25°C unless otherwise specified)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	180	V
Collector-Emitter Voltage	V <sub>CEO</sub>	160	V
Emitter-Base Voltage	V <sub>EBO</sub>	6.0	V
Collector Current - Continuous (Note 1)	I <sub>C</sub>	600	mA

### Thermal Characteristics (@T<sub>A</sub> = +25°C unless otherwise specified)

Characteristic	Symbol	Value	Unit	
Power Dissipation	(Note 5)	$P_{D}$	300	mW
Thermal Resistance, Junction to Ambient	$R_{ heta JA}$	417	°C/W	
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C	

## ESD Ratings (Note 6)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

Notes:

- 5. For a device mounted on minimum recommended pad layout 1oz copper that is on a single-sided FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.
- 6. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

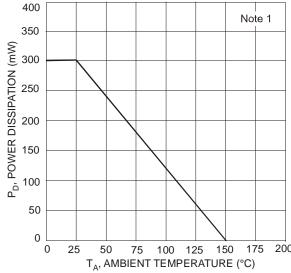


Fig. 1 Power Dissipation vs. Ambient Temperature



# Electrical Characteristics @T<sub>A</sub> = 25°C unless otherwise specified

Characteristic	Symbol	Min	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)					
Collector-Base Breakdown Voltage	V <sub>(BR)CBO</sub>	180	_	V	$I_C = 100\mu A, I_E = 0$
Collector-Emitter Breakdown Voltage	V <sub>(BR)CEO</sub>	160	_	V	$I_C = 1.0 \text{mA}, I_B = 0$
Emitter-Base Breakdown Voltage	V <sub>(BR)EBO</sub>	6.0	_	V	$I_E = 10\mu A, I_C = 0$
Collector Cutoff Current	I <sub>CBO</sub>	_	50	nΑ μΑ	V <sub>CB</sub> = 120V, I <sub>E</sub> = 0 V <sub>CB</sub> = 120V, I <sub>E</sub> = 0, T <sub>A</sub> = 100°C
Emitter Cutoff Current	I <sub>EBO</sub>	_	50	nA	V <sub>EB</sub> = 4.0V, I <sub>C</sub> = 0
ON CHARACTERISTICS (Note 7)			•	ı	, <u></u>
		80	_		I <sub>C</sub> = 1.0mA, V <sub>CE</sub> = 5.0V
DC Current Gain	h <sub>FE</sub>	80	250	_	$I_C = 10 \text{mA}, V_{CE} = 5.0 \text{V}$
		30	_		$I_C = 50 \text{mA}, V_{CE} = 5.0 \text{V}$
Collector-Emitter Saturation Voltage	.,		0.15	V	I <sub>C</sub> = 10mA, I <sub>B</sub> = 1.0mA
Collector-Entitler Saturation voltage	V <sub>CE</sub> (SAT)		0.20	V	$I_C = 50 \text{mA}, I_B = 5.0 \text{mA}$
Base-Emitter Saturation Voltage	V	_	1.0	V	$I_C = 10mA$ , $I_B = 1.0mA$
<b>G</b>	$V_{BE(SAT)}$			V	$I_C = 50 \text{mA}, I_B = 5.0 \text{mA}$
SMALL SIGNAL CHARACTERISTICS					
Output Capacitance	$C_{obo}$		6.0	pF	$V_{CB} = 10V$ , $f = 1.0MHz$ , $I_E = 0$
Small Signal Current Gain	h <sub>fe</sub>	50	250	_	$V_{CE} = 10V, I_{C} = 1.0mA,$ f = 1.0kHz
Current Gain-Bandwidth Product	f <sub>T</sub>	100	300	MHz	V <sub>CE</sub> = 10V, I <sub>C</sub> = 10mA, f = 100MHz
Noise Figure	nF		8.0	dB	$V_{CE} = 5.0V, I_{C} = 200\mu A,$ $R_{S} = 1.0k\Omega, f = 1.0kHz$

Notes: 7. Measured under pulsed conditions. Pulse width  $\leq$  300 $\mu$ s. Duty cycle  $\leq$  2%.



## Typical Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

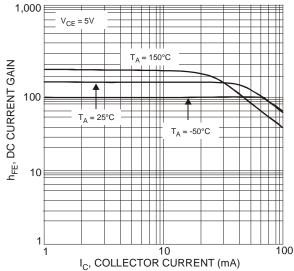
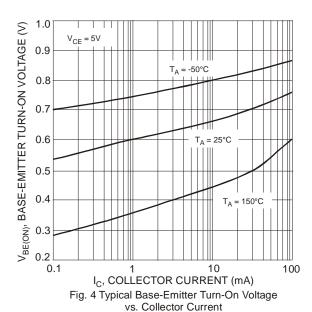


Fig. 2 Typical DC Current Gain vs. Collector Current



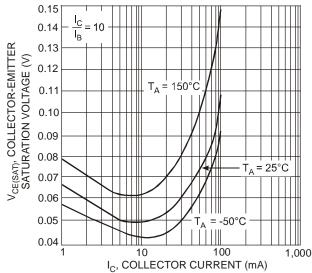


Fig. 3 Typical Collector-Emitter Saturation Voltage vs. Collector Current

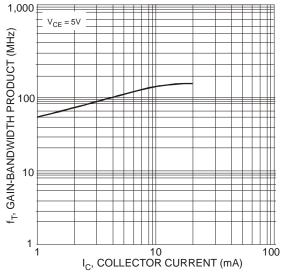
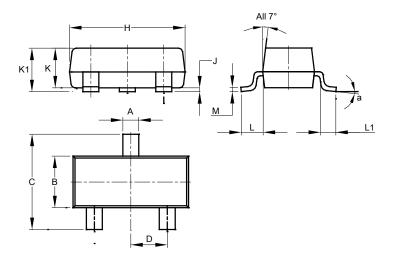


Fig. 5 Typical Gain-Bandwidth Product vs.
Collector Current



# **Package Outline Dimensions**

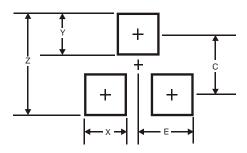
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



SOT23						
Dim	Min	Max	Тур			
Α	0.37	0.51	0.40			
В	1.20	1.40	1.30			
C	2.30	2.50	2.40			
D	0.89	1.03	0.915			
F	0.45	0.60	0.535			
G	1.78	2.05	1.83			
Н	2.80	3.00	2.90			
J	0.013	0.10	0.05			
K	0.890	1.00	0.975			
K1	0.903	1.10	1.025			
L	0.45	0.61	0.55			
L1	0.25	0.55	0.40			
М	0.085	0.150	0.110			
а	8°					
All Dimensions in mm						

## **Suggested Pad Layout**

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



Dimensions	Value (in mm)
Z	2.9
Х	0.8
Y	0.9
С	2.0
Е	1.35



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